## DISCRETE SEMICONDUCTORS

## DATA SHEET

# **BAT93**Schottky barrier diode

Product specification
File under Discrete Semiconductors, SC01

December 1993

## **Philips Semiconductors**



**PHILIPS** 

#### **BAT93**

#### **FEATURES**

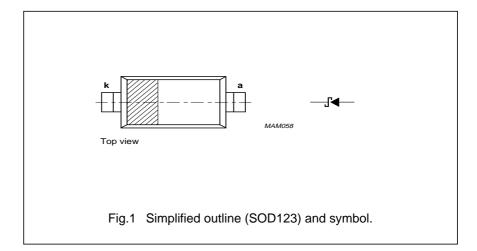
- Ultra-fast switching speed
- · Low forward voltage
- Two-pin SMD package.

#### **DESCRIPTION**

Silicon epitaxial Schottky barrier diode with an integrated guard ring for stress protection.lintended for high speed switching, circuit protection and voltage clamping applications. The diode is encapsulated in a SOD123 SMD plastic package.

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V <sub>R</sub>	continuous reverse voltage		30	V
I <sub>F</sub>	continuous forward current		200	mA
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 mA	400	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 25 V	2	μΑ
Tj	junction temperature		150	°C
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V	10	pF



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#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{R}$	continuous reverse voltage		_	30	V
I <sub>F</sub>	continuous forward current		_	200	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	_	300	mA
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> < 10 ms	_	600	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25°C	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		_	150	°C

#### THERMAL RESISTANCE

SYMBOL	PARAMETER	THERMAL RESISTANCE	
R <sub>th j-a</sub>	from junction to ambient; note 1	500 K/W	

#### Note

1. Printed-circuit board mounting (SOD123 standard conditions).

#### **CHARACTERISTICS**

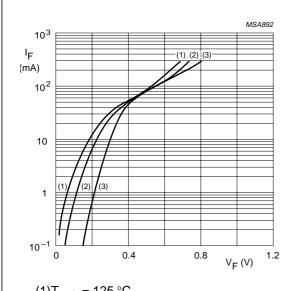
 $T_i = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 0.1 mA	-	240	mV
		I <sub>F</sub> = 1 mA	_	320	mV
		I <sub>F</sub> = 10 mA	-	400	mV
		I <sub>F</sub> = 30 mA	-	500	mV
		I <sub>F</sub> = 100 mA	_	800	mV
V <sub>(BR)R</sub>	reverse breakdown voltage	I <sub>R</sub> = 10 μA	30	_	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 25 V; note 1	_	2	μΑ
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz	_	10	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F$ = 10 mA to $I_R$ = 10 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 1 mA	_	5	ns

#### Note

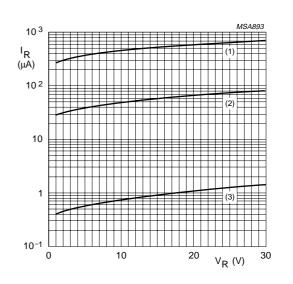
1. Pulsed test:  $t_p$  = 300  $\mu$ s;  $\delta$  = 0.02.

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- $(1)T_{amb} = 125 \, ^{\circ}C.$
- $(2)T_{amb} = 85 \, ^{\circ}C.$
- $(3)T_{amb} = 25 \, {}^{\circ}C.$

Fig.2 Forward current as a function of forward voltage.



- $(1)T_{amb} = 125 \, ^{\circ}C.$
- $(2)T_{amb} = 85 \, ^{\circ}C.$
- $(3)T_{amb} = 25 \, ^{\circ}C.$

Fig.3 Reverse current as a function of reverse voltage.

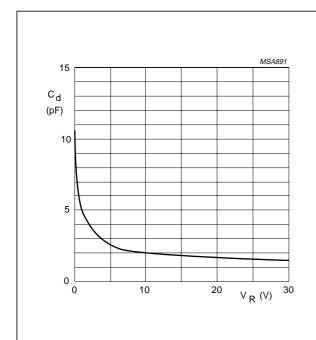
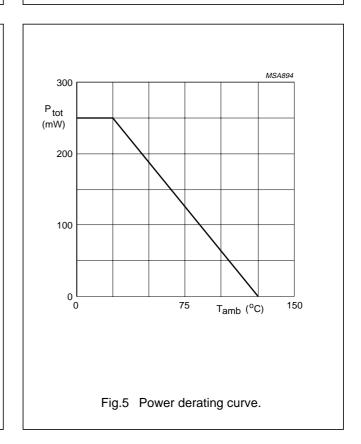
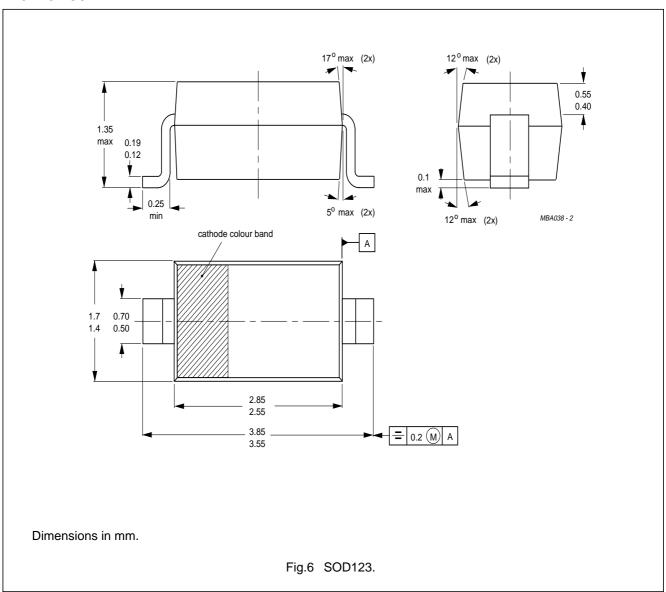


Fig.4 Diode capacitance as a function of reverse voltage.



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#### **PACKAGE OUTLINE**



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#### **DEFINITIONS**

Data Sheet Status		
Objective specification This data sheet contains target or goal specifications for product development.		
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.	
Product specification	This data sheet contains final product specifications.	
Limiting values		

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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